19-5618; Rev 0; 12/10

Dual 50MHz to 1000MHz High-Linearity, Serial/Analog-Controlled VGA

General Description

The MAX2064 high-linearity, dual analog variable-gain amplifier (VGA) operates in the 50MHz to 1000MHz frequency range. Each analog attenuator is controlled using an external voltage, or through the SPI™-compatible interface using an on-chip 8-bit DAC.

Since each of the stages has its own external RF input and RF output, this component can be configured to either optimize noise figure (NF) (amplifier configured first) or OIP3 (amplifier last). The device's performance features include 24dB amplifier gain (amplifier only), 4.4dB NF at maximum gain (includes attenuator insertion losses), and a high OIP3 level of +41dBm. Each of these features makes the device an ideal VGA for multipath receiver and transmitter applications.

In addition, the device operates from a single +5V supply with full performance, or a +3.3V supply for an enhanced power-savings mode with lower performance. The device is available in a compact 48-pin TQFN package (7mm x 7mm) with an exposed pad. Electrical performance is guaranteed over the extended temperature range, from T_C = -40°C to +85°C.

Applications

IF and RF Gain Stages

Temperature-Compensation Circuits

WCDMA, TD-SCDMA, and cdma2000® Base Stations

GSM 850/GSM 900 EDGE Base Stations

WiMAX™, LTE, and TD-LTE Base Stations and Customer-Premise Equipment

Fixed Broadband Wireless Access

Wireless Local Loop

Military Systems

Features

- **Independently Controlled Dual Paths**
- **50MHz to 1000MHz RF Frequency Range**
- **Pin-Compatible Family Includes**
  - **MAX2062 (Analog/Digital VGA)**
  - **MAX2063 (Digital-Only VGA)**
- **22dB (typ) Maximum Gain**
- **0.19dB Gain Flatness Over 100MHz Bandwidth**
- **33dB Gain Range**
- **49dB Path Isolation (at 200MHz)**
- **Built-In 8-Bit DACs for Analog Attenuation Control**
- **Excellent Linearity at 200MHz (Configured with Amp Last)**
  - **+41dBm OIP3**
  - **+59dBm OIP2**
  - **+19dBm Output 1dB Compression Point**
- **4.4dB Typical Noise Figure (at 200MHz)**
- **Single +5V Supply (or +3.3V Operation)**
- **Amplifier Power-Down Mode for TDD Applications**

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX2064ETM+	-40°C to +85°C	48 TQFN-EP*
MAX2064ETM+T	-40°C to +85°C	48 TQFN-EP*

+Denotes a lead(Pb)-free/RoHS-compliant package.
**EP = Exposed pad.*
T = Tape and reel.

SPI is a trademark of Motorola, Inc.

cdma2000 is a registered trademark of Telecommunications Industry Association.

WiMAX is a trademark of WiMAX Forum.

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

Dual 50MHz to 1000MHz High-Linearity, Serial/Analog-Controlled VGA

ABSOLUTE MAXIMUM RATINGS

$V_{CC_AMP_1}$, $V_{CC_AMP_2}$, V_{CC_RG} to GND .....-0.3V to +5.5V
PD_1, PD_2, AMPSET to GND .....-0.3V to +3.6V
A_VCTL_1, A_VCTL_2 to GND.....-0.3V to +3.6V
DAT, $\overline{CS}$, CLK, AA_SP to GND .....-0.3V to +3.6V
AMP_IN_1, AMP_IN_2 to GND.....+0.95V to +1.2V
AMP_OUT_1, AMP_OUT_2 to GND .....-0.3V to +5.5V
A_ATT_IN_1, A_ATT_IN_2, A_ATT_OUT_1, A_ATT_OUT_2 to GND .....0V to +3.6V
REG_OUT to GND.....-0.3V to +3.6V
RF Input Power (A_ATT_IN_1, A_ATT_IN_2)..... +20dBm
RF Input Power (AMP_IN_1, AMP_IN_2)..... +18dBm
θ_{JC} (Notes 1, 2)..... +12.3°C/W
θ_{JA} (Notes 2, 3)..... +38°C/W
Continuous Power Dissipation (Note 1) 5.3W
Operating Case Temperature Range (Note 4) .. -40°C to +85°C
Junction Temperature .....+150°C
Storage Temperature Range..... -65°C to +150°C
Lead Temperature (soldering, 10s) .....+300°C
Soldering Temperature (reflow) .....+260°C

Note 1: Based on junction temperature $T_J = T_C + (\theta_{JC} \times V_{CC} \times I_{CC})$. This formula can be used when the temperature of the exposed pad is known while the device is soldered down to a PCB. See the *Applications Information* section for details. The junction temperature must not exceed +150°C.

Note 2: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to **www.maxim-ic.com/thermal-tutorial**.

Note 3: Junction temperature $T_J = T_A + (\theta_{JA} \times V_{CC} \times I_{CC})$. This formula can be used when the ambient temperature of the PCB is known. The junction temperature must not exceed +150°C.

Note 4: T_C is the temperature on the exposed pad of the package. T_A is the ambient temperature of the device and PCB.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

+5V SUPPLY DC ELECTRICAL CHARACTERISTICS

(*Typical Application Circuit*, $V_{CC} = V_{CC_AMP_1} = V_{CC_AMP_2} = V_{CC_RG}$ = +4.75V to +5.25V, AMPSET = 0, PD_1 = PD_2 = 0, T_C = -40°C to +85°C. Typical values are at $V_{CC_}$ = +5.0V and T_C = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{CC}		4.75	5	5.25	V
Supply Current	I_{DC}			143	210	mA
Power-Down Current	I_{DCPD}	PD_1 = PD_2 = 1, V_{IH} = 3.3V		5.3	8	mA
Input Low Voltage	V_{IL}				0.5	V
Input High Voltage	V_{IH}		1.7		3.465	V
Input Logic Current	I_{IH}, I_{IL}		-1		+1	µA

+3.3V SUPPLY DC ELECTRICAL CHARACTERISTICS

(*Typical Application Circuit*, $V_{CC} = V_{CC_AMP_1} = V_{CC_AMP_2} = V_{CC_RG}$ = +3.135V to +3.465V, AMPSET = 1, PD_1 = PD_2 = 0, T_C = -40°C to +85°C. Typical values are at $V_{CC_}$ = +3.3V and T_C = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{CC}		3.135	3.3	3.465	V
Supply Current	I_{DC}			84.7	145	mA
Power-Down Current	I_{DCPD}	PD_1 = PD_2 = 1, V_{IH} = 3.3V		4.5	8	mA
Input Low Voltage	V_{IL}			0.5		V
Input High Voltage	V_{IH}			1.7		V

RECOMMENDED AC OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
RF Frequency	f_{RF}	(Note 5)	50		1000	MHz

+5V SUPPLY AC ELECTRICAL CHARACTERISTICS (each path, unless otherwise noted)

(*Typical Application Circuit*, V_{CC} = $V_{CC_AMP_1}$ = $V_{CC_AMP_2}$ = V_{CC_RG} = +4.75V to +5.25V, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 0, PD_1 = PD_2 = 0, 100MHz ≤ f_{RF} ≤ 500MHz, T_C = -40°C to +85°C. Typical values are at maximum gain setting, V_{CC} = +5.0V, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.) (Note 6)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small-Signal Gain	G	f_{RF} = 50MHz		22.4		dB
		f_{RF} = 100MHz		22.3		
		f_{RF} = 200MHz		22.2		
		f_{RF} = 350MHz, T_C = +25°C	19.5	21.9	23.5	
		f_{RF} = 450MHz		21.7		
		f_{RF} = 750MHz		21.4		
		f_{RF} = 900MHz		20.6		
Gain vs. Temperature				-0.006		dB/°C
Gain Flatness vs. Frequency		From 100MHz to 200MHz		0.18		dB
		Any 100MHz frequency band from 200MHz to 500MHz		0.19		
Noise Figure	NF	f_{RF} = 50MHz		4.4		dB
		f_{RF} = 100MHz		4.4		
		f_{RF} = 200MHz		4.4		
		f_{RF} = 350MHz		4.6		
		f_{RF} = 450MHz		4.7		
		f_{RF} = 750MHz		5.3		
		f_{RF} = 900MHz		5.7		
Total Attenuation Range		f_{RF} = 350MHz, T_C = +25°C	30	32.9		dB
Output Second-Order Intercept Point	OIP2	P_{OUT} = 0dBm/tone, Δf = 1MHz, $f_1 + f_2$		53.7		dBm
Path Isolation		RF input 1 amplified power measured at RF output 2 relative to RF output 1, all unused ports terminated to 50Ω		48.7		dB
		RF input 2 amplified signal measured at RF output 1 relative to RF output 2, all unused ports terminated to 50Ω		48.6		
Output Third-Order Intercept Point	OIP3	P_{OUT} = 0dBm/tone, Δf = 1MHz, f_{RF} = 50MHz		46.3		dBm
		P_{OUT} = 0dBm/tone, Δf = 1MHz, f_{RF} = 100MHz		44.2		
		P_{OUT} = 0dBm/tone, Δf = 1MHz, f_{RF} = 200MHz		41.1		
		P_{OUT} = 0dBm/tone, Δf = 1MHz, f_{RF} = 350MHz		37.1		
		P_{OUT} = 0dBm/tone, Δf = 1MHz, f_{RF} = 450MHz		34.9		
		P_{OUT} = 0dBm/tone, Δf = 1MHz, f_{RF} = 750MHz		28.2		
		P_{OUT} = 0dBm/tone, Δf = 1MHz, f_{RF} = 900MHz		24.6		

Dual 50MHz to 1000MHz High-Linearity, Serial/Analog-Controlled VGA

+5V SUPPLY AC ELECTRICAL CHARACTERISTICS (each path, unless otherwise noted) (continued)

(*Typical Application Circuit*, V_{CC} = $V_{CC_AMP_1}$ = $V_{CC_AMP_2}$ = V_{CC_RG} = +4.75V to +5.25V, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 0, PD_1 = PD_2 = 0, 100MHz ≤ f_{RF} ≤ 500MHz, T_C = -40°C to +85°C. Typical values are at maximum gain setting, V_{CC} = +5.0V, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.) (Note 6)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Output -1dB Compression Point	P_{1dB}	f_{RF} = 350MHz, T_C = +25°C (Note 7)		17	18.7		dBm
Second Harmonic		P_{OUT} = +3dBm			-56.7		dBc
Third Harmonic		P_{OUT} = +3dBm			-72.4		dBc
Group Delay		Includes EV kit PCB delays			0.9		ns
Amplifier Power-Down Time		PD_1 or PD_2 from 0 to 1, amplifier DC supply current settles to within 0.1mA			0.5		µs
Amplifier Power-Up Time		PD_1 or PD_2 from 1 to 0, amplifier DC supply current settles to within 1%			0.5		µs
Input Return Loss	RL_{IN}	50Ω source			16.8		dB
Output Return Loss	RL_{OUT}	50Ω load			30.7		dB
ANALOG ATTENUATOR (each path, unless otherwise noted)							
Insertion Loss	IL				2.2		dB
Input Second-Order Intercept Point	IIP2	P_{IN1} = 0dBm, P_{IN2} = 0dBm (minimum attenuation), Δf = 1MHz, $f_1 + f_2$			61.9		dBm
Input Third-Order Intercept Point	IIP3	P_{IN1} = 0dBm, P_{IN2} = 0dBm (minimum attenuation), Δf = 1MHz			37.0		dBm
Attenuation Range					32.9		dB
Gain Control Slope		Analog control input			-13.3		dB/V
Maximum Gain Control Slope		Over analog control input range			-35.2		dB/V
Insertion Phase Change		Over analog control input range			16.5		Deg/V
Attenuator Response Time		RF settled to within ±0.5dB	31dB to 0dB, AA_SP = 0, from A_VCTL_ step		500		ns
			31dB to 0dB, AA_SP = 1, from $\overline{CS}$ step		500		
			0dB to 31dB, AA_SP = 0, from A_VCTL_ step		500		
			0dB to 31dB, AA_SP = 1, from $\overline{CS}$ step		500		
Group Delay vs. Control Voltage		Over analog control input from 0.25V to 2.75V			-0.26		ns
Analog Control Input Range				0.25		2.75	V
Analog Control Input Impedance					19.2		kΩ
Input Return Loss		50Ω source			16.0		dB
Output Return Loss		50Ω load			15.9		dB

+5V SUPPLY AC ELECTRICAL CHARACTERISTICS (each path, unless otherwise noted) (continued)

(*Typical Application Circuit*, $V_{CC} = V_{CC_AMP_1} = V_{CC_AMP_2} = V_{CC_RG}$ = +4.75V to +5.25V, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 0, PD_1 = PD_2 = 0, 100MHz ≤ f_{RF} ≤ 500MHz, T_C = -40°C to +85°C. Typical values are at maximum gain setting, V_{CC} = +5.0V, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.) (Note 6)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
D/A CONVERTER						
Number of Bits				8		Bits
Output Voltage		DAC code = 00000000			0.35	V
		DAC code = 11111111	2.7			
SERIAL PERIPHERAL INTERFACE (SPI)						
Maximum Clock Speed				20		MHz
Data-to-Clock Setup Time	t_{CS}			2		ns
Data-to-Clock Hold Time	t_{CH}			2.5		ns
Clock-to-$\overline{CS}$ Setup Time	t_{ES}			3		ns
$\overline{CS}$ Positive Pulse Width	t_{EW}			7		ns
$\overline{CS}$ Setup Time	t_{EWS}			3.5		ns
Clock Pulse Width	t_{CW}			5		ns

+3.3V SUPPLY AC ELECTRICAL CHARACTERISTICS (each path, unless otherwise noted)

(*Typical Application Circuit*, $V_{CC} = V_{CC_AMP_1} = V_{CC_AMP_2} = V_{CC_RG}$ = +3.135V to +3.465V, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 1, PD_1 = PD_2 = 0, 100MHz ≤ f_{RF} ≤ 500MHz, T_C = -40°C to +85°C. Typical values are at maximum gain setting, V_{CC} = +3.3V, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.) (Note 6)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small-Signal Gain	G			21.8		dB
Output Third-Order Intercept Point	OIP3	P_{OUT} = 0dBm/tone		29.1		dBm
Noise Figure	NF			4.8		dB
Total Attenuation Range				32.9		dB
Path Isolation		RF input 1 amplified power measured at RF output 2 relative to RF output 1, all unused ports terminated to 50Ω		48.1		dB
		RF input 2 amplified signal measured at RF output 1 relative to RF output 2, all unused ports terminated to 50Ω		48.2		
Output -1dB Compression Point	P_{1dB}	(Note 7)		13.2		dBm

Note 5: Operation outside this range is possible, but with degraded performance of some parameters. See the *Typical Operating Characteristics*.

Note 6: All limits include external component losses. Output measurements are performed at the RF output port of the *Typical Application Circuit*.

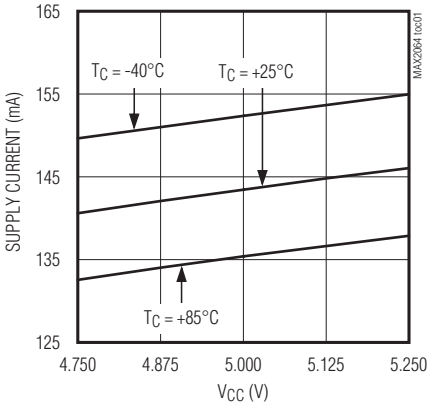
Note 7: It is advisable not to continuously operate the RF input 1 or RF input 2 above +15dBm.

Dual 50MHz to 1000MHz High-Linearity, Serial/Analog-Controlled VGA

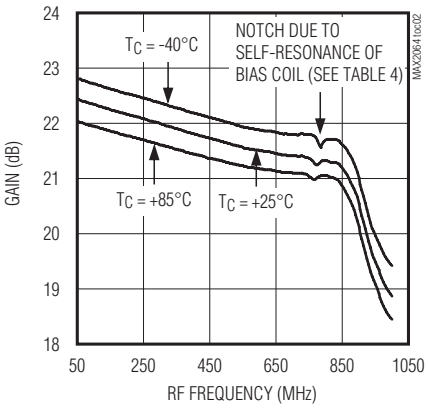
Typical Operating Characteristics

(*Typical Application Circuit*, **V_{CC} = $V_{CC_AMP_1}$ = $V_{CC_AMP_2}$ = V_{CC_RG} = +5V**, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 0, PD_1 = PD_2 = 0, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.)

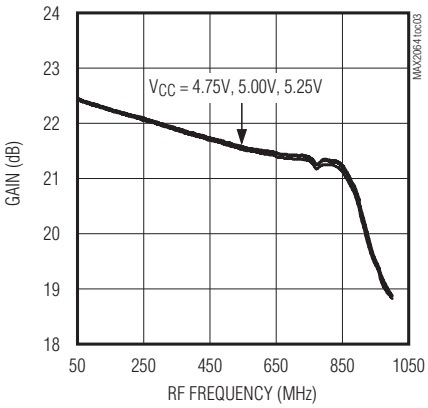
SUPPLY CURRENT vs. SUPPLY VOTAGE



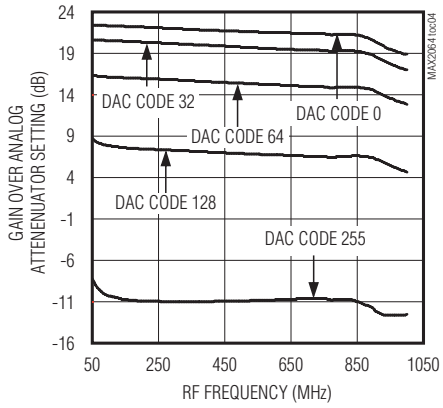
GAIN vs. RF FREQUENCY



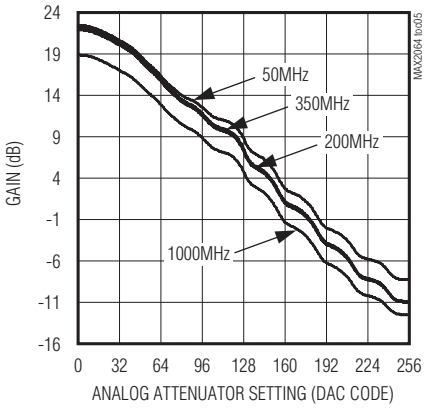
GAIN vs. RF FREQUENCY



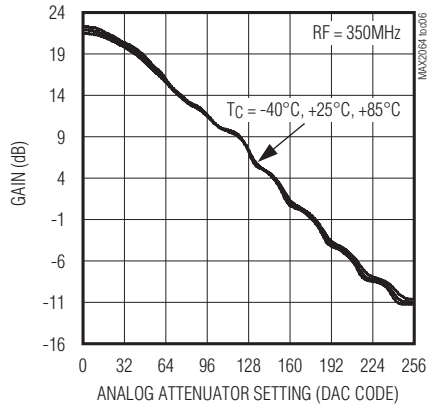
GAIN OVER ANALOG ATTENUATOR SETTING vs. RF FREQUENCY



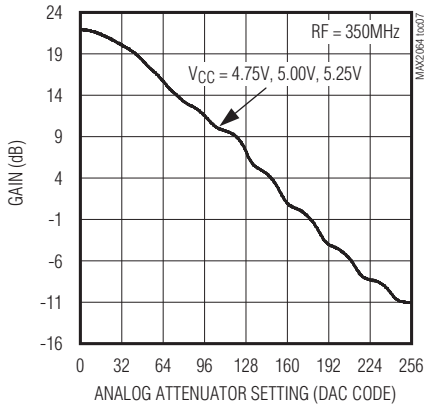
GAIN vs. ANALOG ATTENUATOR SETTING



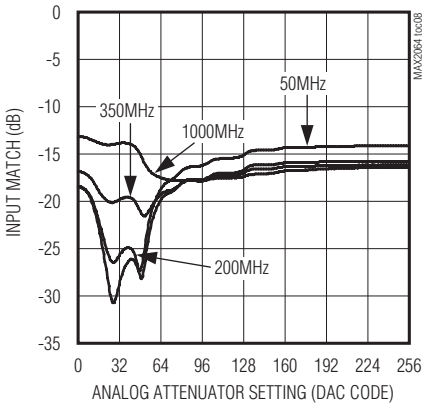
GAIN vs. ANALOG ATTENUATOR SETTING



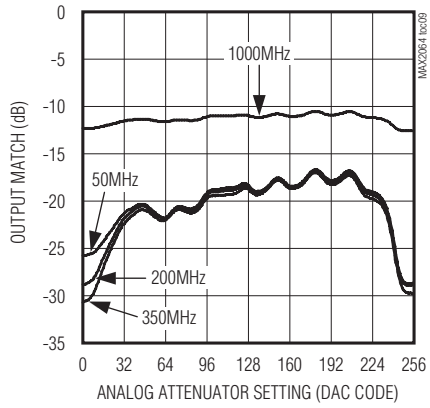
GAIN vs. ANALOG ATTENUATOR SETTING



INPUT MATCH vs. ANALOG ATTENUATOR SETTING



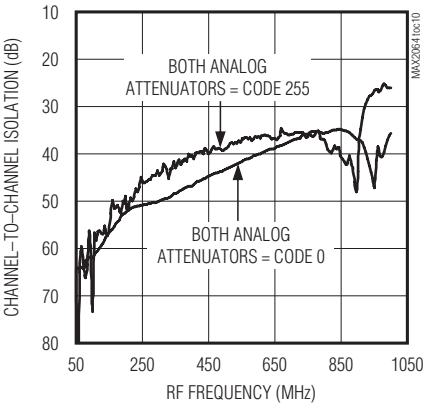
OUTPUT MATCH vs. ANALOG ATTENUATOR SETTING



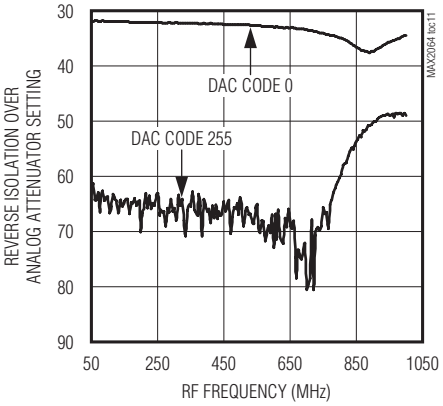
Typical Operating Characteristics (continued)

(*Typical Application Circuit*, **V_{CC} = $V_{CC_AMP_1}$ = $V_{CC_AMP_2}$ = V_{CC_RG} = +5V**, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 0, PD_1 = PD_2 = 0, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.)

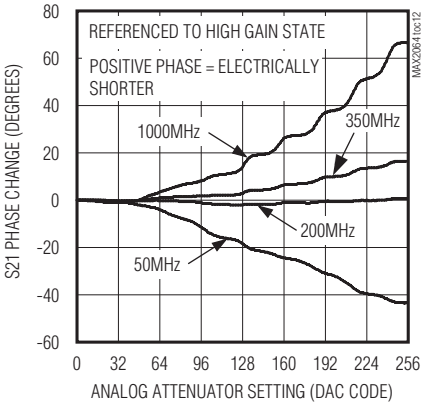
CHANNEL–TO–CHANNEL ISOLATION vs. RF FREQUENCY



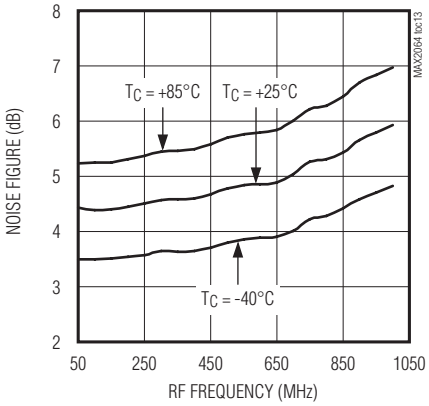
REVERSE ISOLATION OVER ANALOG ATTENUATOR SETTING vs. RF FREQUENCY



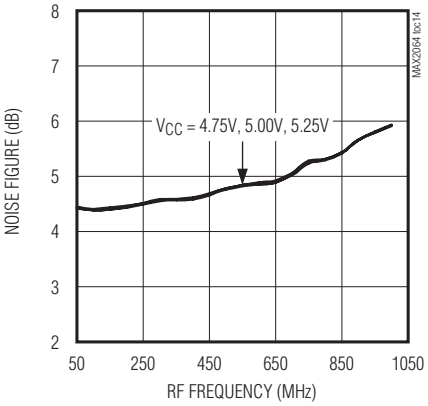
S21 PHASE CHANGE vs. ANALOG ATTENUATOR SETTING



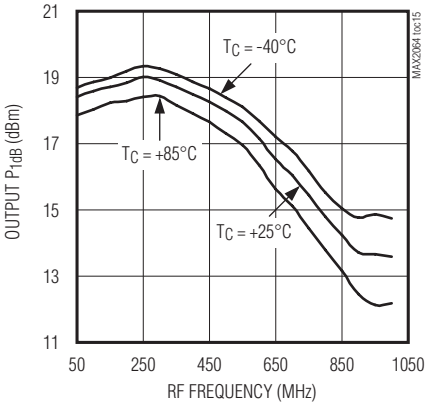
NOISE FIGURE vs. RF FREQUENCY



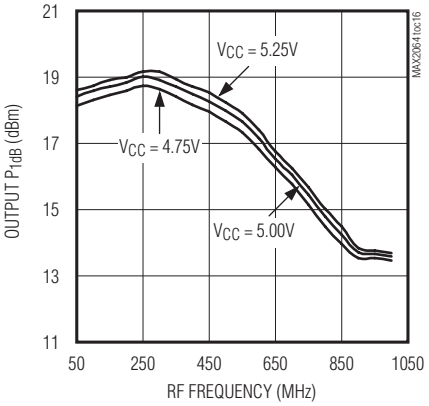
NOISE FIGURE vs. RF FREQUENCY



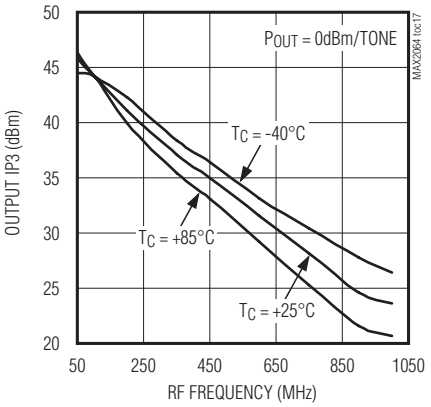
OUTPUT P_{1dB} vs. RF FREQUENCY



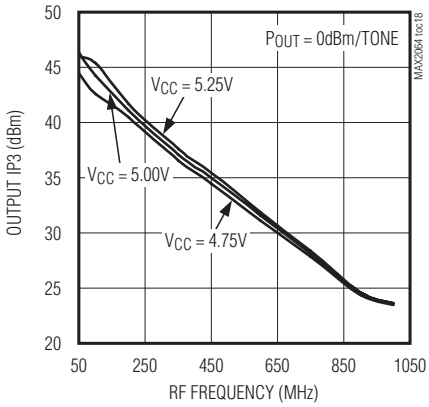
OUTPUT P_{1dB} vs. RF FREQUENCY



OUTPUT IP3 vs. RF FREQUENCY



OUTPUT IP3 vs. RF FREQUENCY

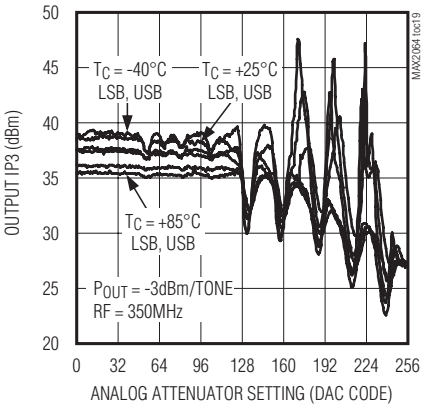


Dual 50MHz to 1000MHz High-Linearity, Serial/Analog-Controlled VGA

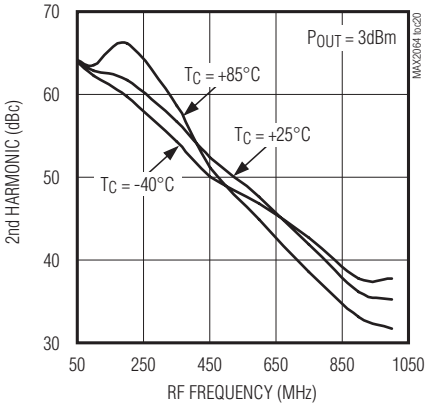
Typical Operating Characteristics (continued)

(*Typical Application Circuit*, **V_{CC} = $V_{CC_AMP_1}$ = $V_{CC_AMP_2}$ = V_{CC_RG} = +5V**, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 0, PD_1 = PD_2 = 0, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.)

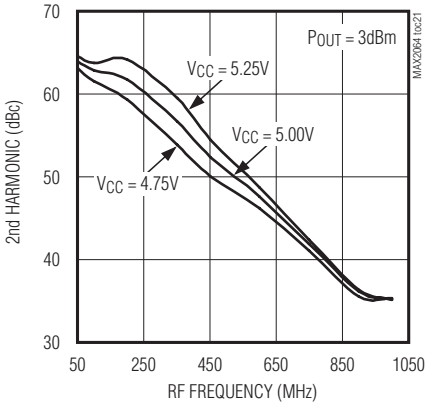
OUTPUT IP3 vs. ANALOG ATTENUATOR SETTING



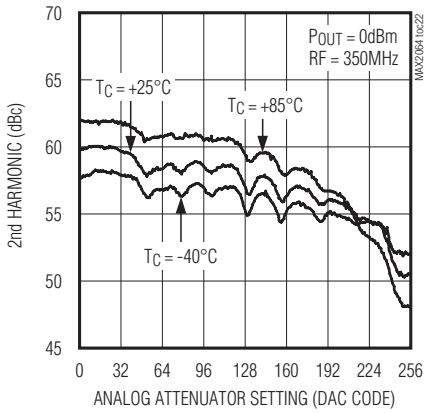
2nd HARMONIC vs. RF FREQUENCY



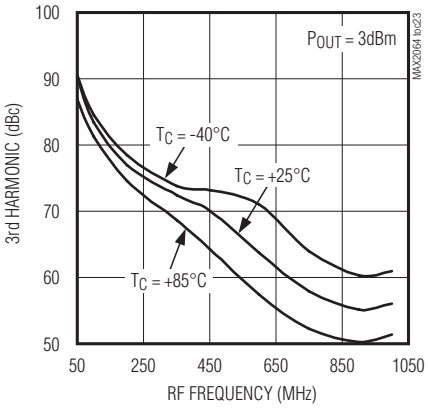
2nd HARMONIC vs. RF FREQUENCY



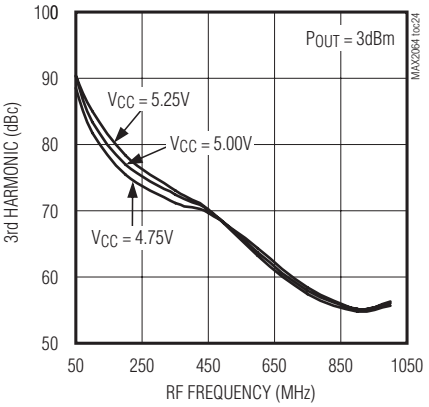
2nd HARMONIC vs. ANALOG ATTENUATOR SETTING



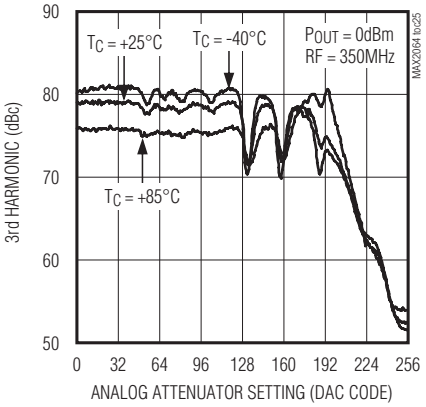
3rd HARMONIC vs. RF FREQUENCY



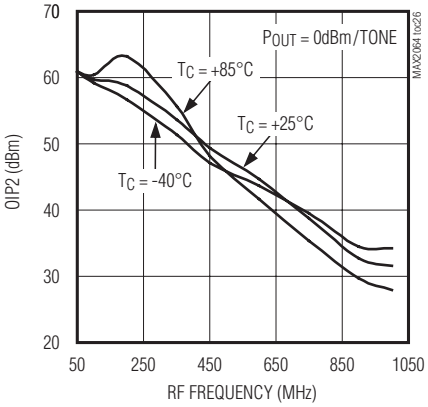
3rd HARMONIC vs. RF FREQUENCY



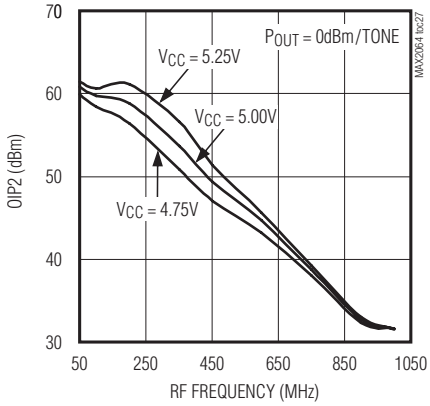
3rd HARMONIC vs. ANALOG ATTENUATOR SETTING



OIP2 vs. RF FREQUENCY



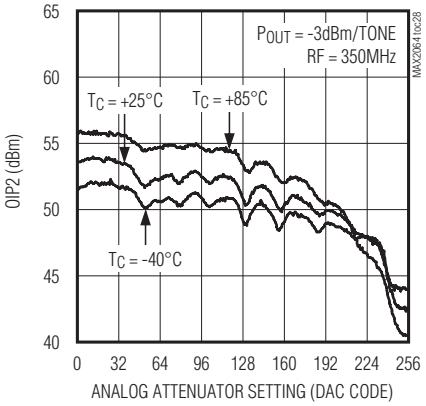
OIP2 vs. RF FREQUENCY



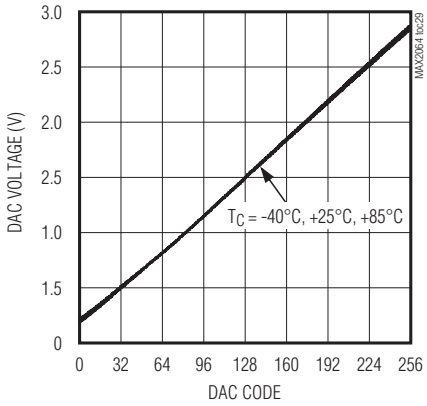
Typical Operating Characteristics (continued)

(*Typical Application Circuit*, **V_{CC} = $V_{CC_AMP_1}$ = $V_{CC_AMP_2}$ = V_{CC_RG} = +5V**, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 0, PD_1 = PD_2 = 0, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.)

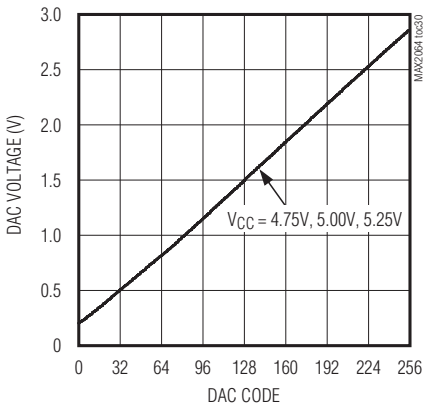
OIP2 vs. ANALOG ATTENUATOR SETTING



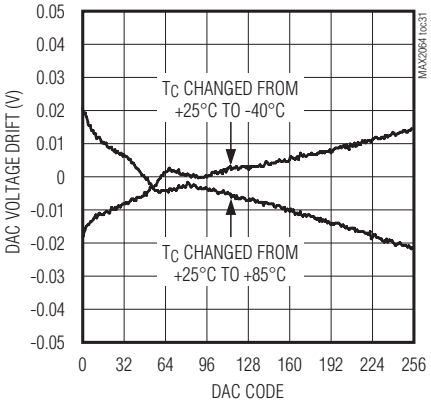
DAC VOLTAGE vs. DAC CODE



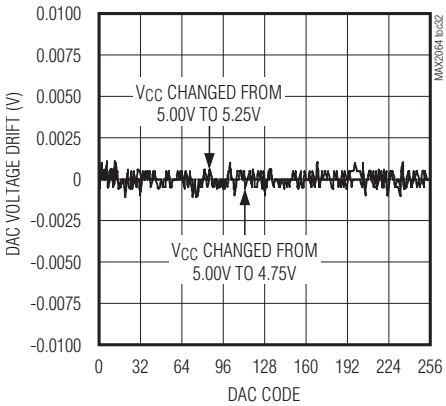
DAC VOLTAGE vs. DAC CODE



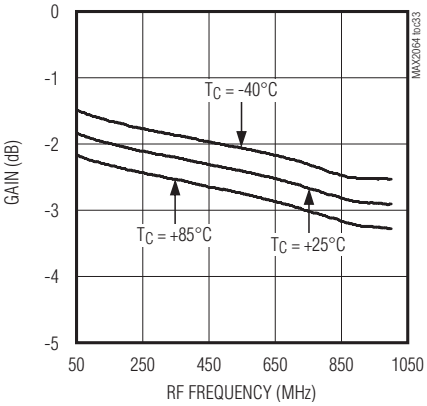
DAC VOLTAGE DRIFT vs. DAC CODE



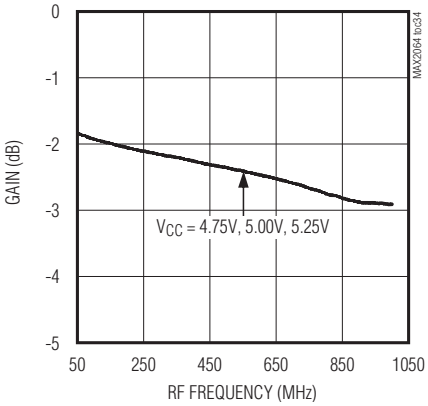
DAC VOLTAGE DRIFT vs. DAC CODE



GAIN vs. RF FREQUENCY (ANALOG ATTENUATOR ONLY)



GAIN vs. RF FREQUENCY (ANALOG ATTENUATOR ONLY)

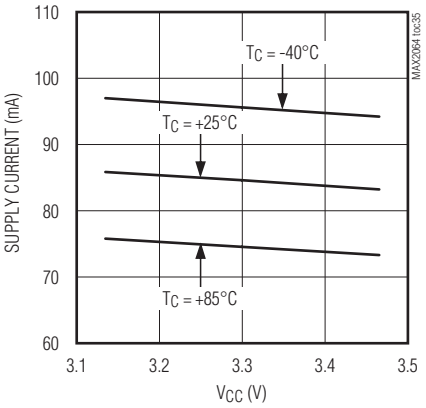


Dual 50MHz to 1000MHz High-Linearity, Serial/Analog-Controlled VGA

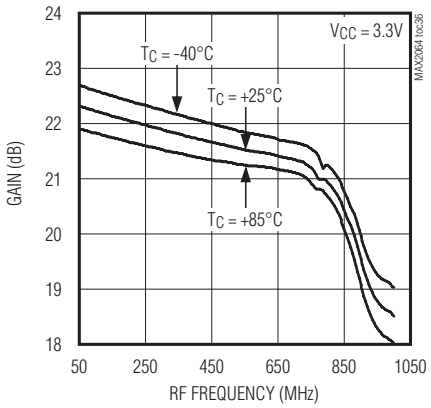
Typical Operating Characteristics

(*Typical Application Circuit*, **V_{CC} = $V_{CC_AMP_1}$ = $V_{CC_AMP_2}$ = V_{CC_RG} = +3.3V**, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 1, PD_1 = PD_2 = 0, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.)

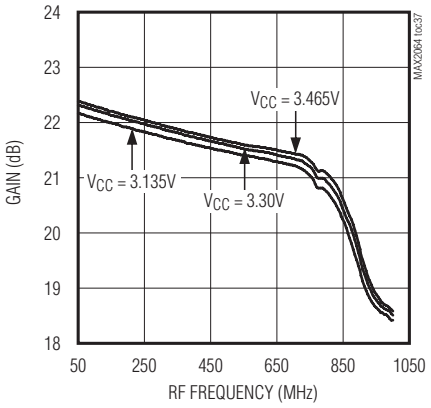
SUPPLY CURRENT vs. SUPPLY VOLTAGE



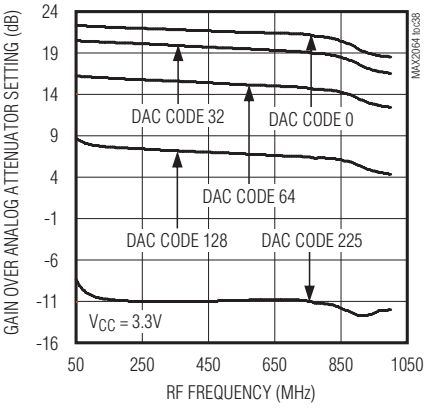
GAIN vs. RF FREQUENCY



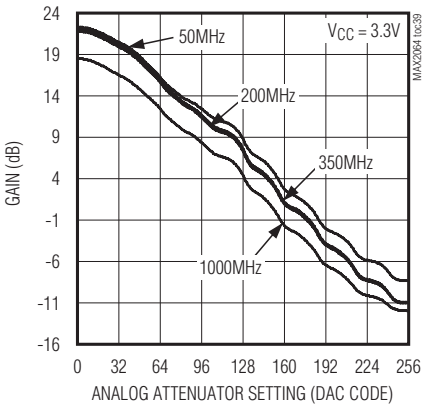
GAIN vs. RF FREQUENCY



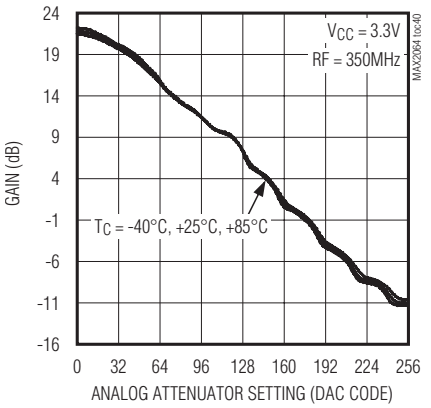
GAIN OVER ANALOG ATTENUATOR SETTING vs. RF FREQUENCY



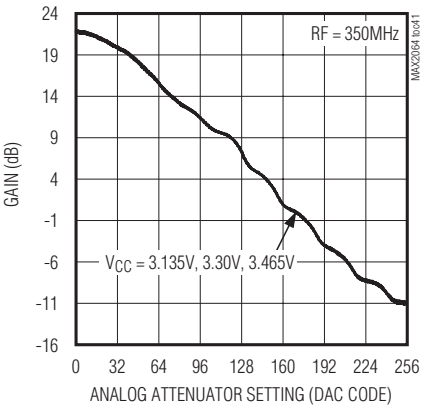
GAIN vs. ANALOG ATTENUATOR SETTING



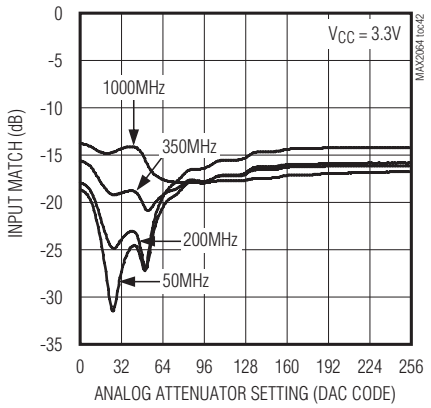
GAIN vs. ANALOG ATTENUATOR SETTING



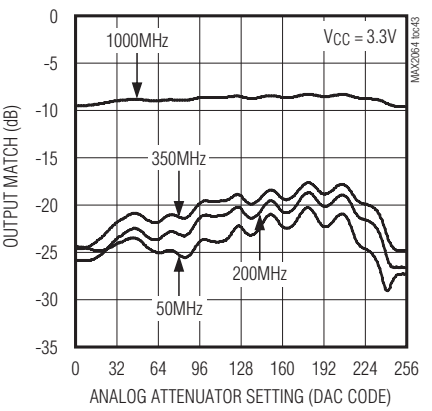
GAIN vs. ANALOG ATTENUATOR SETTING



INPUT MATCH vs. ANALOG ATTENUATOR SETTING



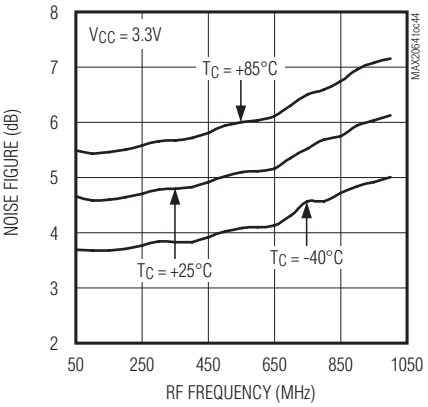
OUTPUT MATCH vs. ANALOG ATTENUATOR SETTING



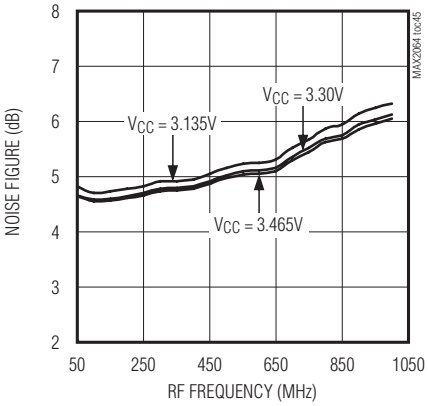
Typical Operating Characteristics (continued)

(*Typical Application Circuit*, **V_{CC} = $V_{CC_AMP_1}$ = $V_{CC_AMP_2}$ = V_{CC_RG} = +3.3V**, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 1, PD_1 = PD_2 = 0, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.)

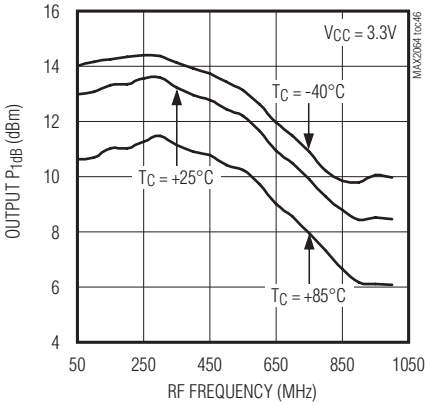
NOISE FIGURE vs. RF FREQUENCY



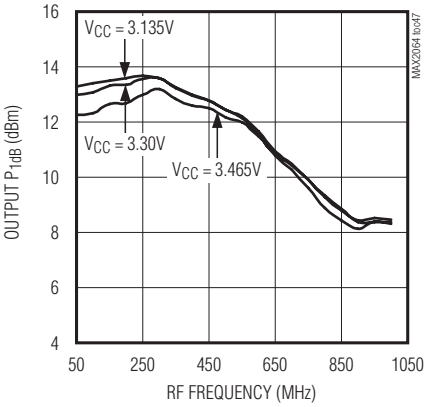
NOISE FIGURE vs. RF FREQUENCY



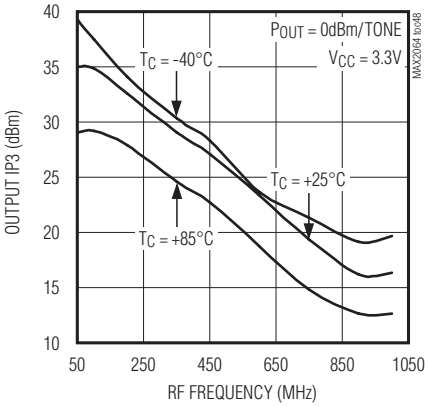
OUTPUT P_{1dB} vs. RF FREQUENCY



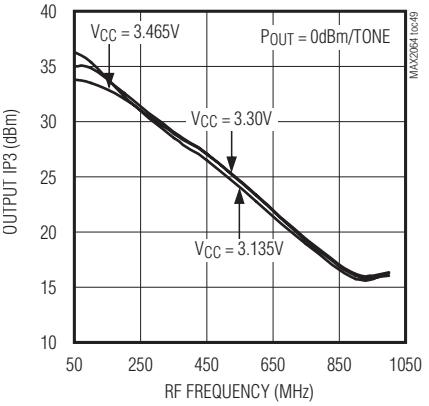
OUTPUT P_{1dB} vs. RF FREQUENCY



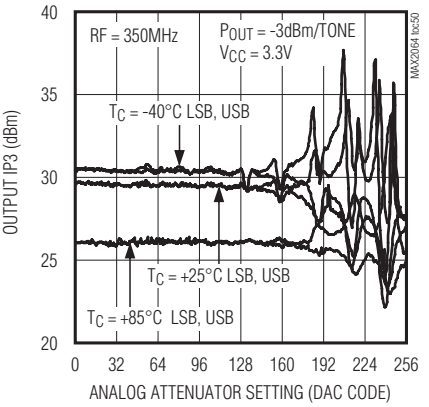
OUTPUT IP3 vs. RF FREQUENCY



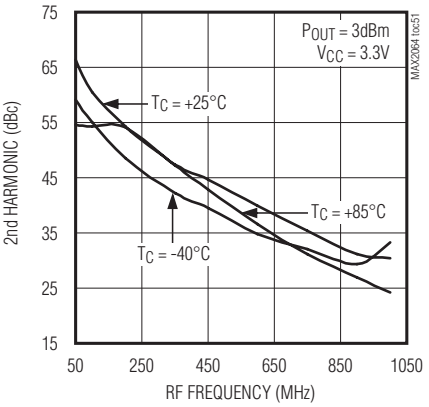
OUTPUT IP3 vs. RF FREQUENCY



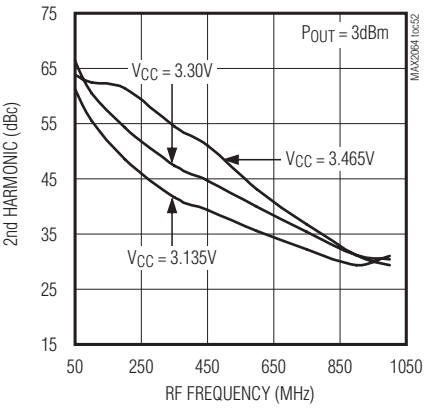
OUTPUT IP3 vs. ANALOG ATTENUATOR SETTING



2nd HARMONIC vs. RF FREQUENCY



2nd HARMONIC vs. RF FREQUENCY

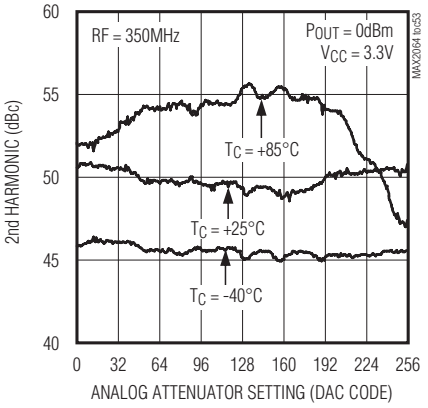


Dual 50MHz to 1000MHz High-Linearity, Serial/Analog-Controlled VGA

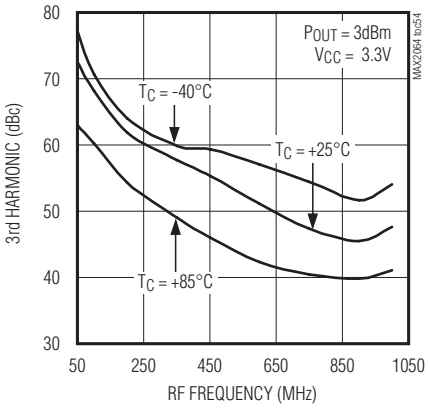
Typical Operating Characteristics (continued)

(*Typical Application Circuit*, **V_{CC} = $V_{CC_AMP_1}$ = $V_{CC_AMP_2}$ = V_{CC_RG} = +3.3V**, attenuators are set for maximum gain, RF ports are driven from 50Ω sources, AMPSET = 1, PD_1 = PD_2 = 0, P_{IN} = -20dBm, f_{RF} = 350MHz, and T_C = +25°C, unless otherwise noted.)

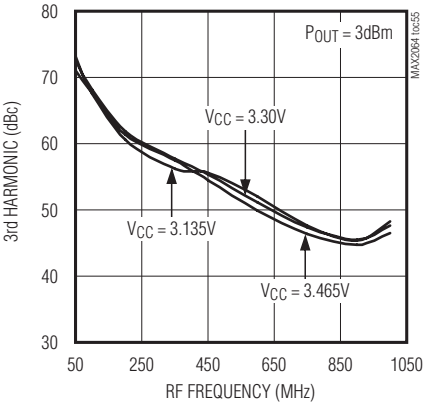
2nd HARMONIC vs. ANALOG ATTENUATOR SETTING



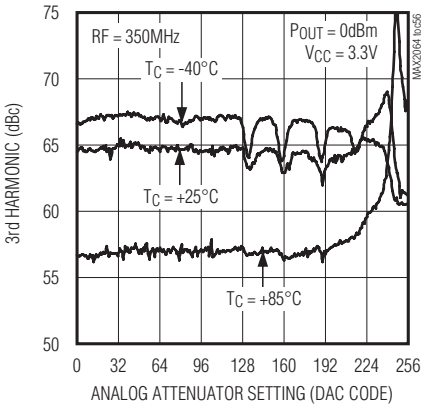
3rd HARMONIC vs. RF FREQUENCY



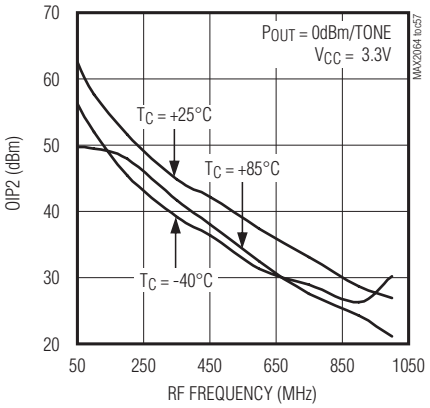
3rd HARMONIC vs. RF FREQUENCY



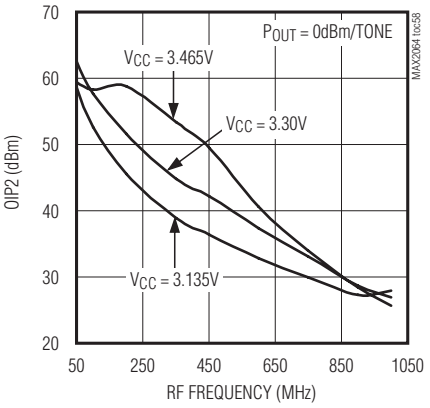
3rd HARMONIC vs. ANALOG ATTENUATOR SETTING



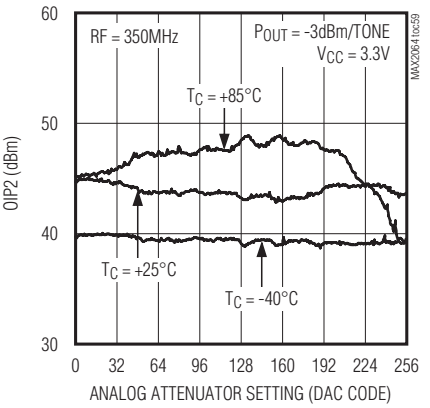
OIP2 vs. RF FREQUENCY



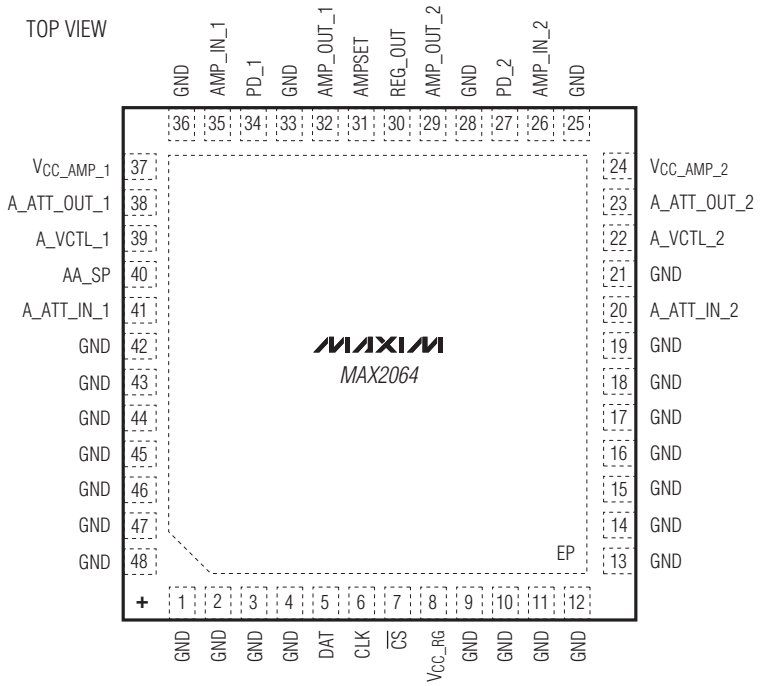
OIP2 vs. RF FREQUENCY



OIP2 vs. ANALOG ATTENUATOR SETTING



Pin Configuration



Pin Description

PIN	NAME	FUNCTION
1–4, 9–19, 21, 25, 28, 33, 36, 42–48	GND	Ground
5	DAT	SPI Data Digital Input
6	CLK	SPI Clock Digital Input
7	$\overline{CS}$	SPI Chip-Select Digital Input
8	V_{CC_RG}	Regulator Supply Input. Connect to a 3.3V or 5V external power supply. V_{CC_RG} powers all circuits except for the driver amplifiers. Bypass with a 10nF capacitor as close as possible to the pin.
20	A_ATT_IN_2	Analog Attenuator Input (50Ω), Path 2. Requires a 1000pF DC-blocking capacitor.
22	A_VCTL_2	Analog Attenuator Voltage-Control Input, Path 2. Bypass to ground with a 150pF capacitor if DAC 2 is used (AA_SP = 1).
23	A_ATT_OUT_2	Analog Attenuator Output (50Ω), Path 2. Requires a DC-blocking capacitor. Connect to AMP_IN_2 through a 1000pF capacitor.
24	$V_{CC_AMP_2}$	Driver Amplifier Supply-Voltage Input, Path 2. Bypass with a 10nF capacitor as close as possible to the pin.
26	AMP_IN_2	Driver Amplifier Input (50Ω), Path 2. Requires a DC-blocking capacitor. Connect to A_ATT_OUT_2 through a 1000pF capacitor.
27	PD_2	Power-Down, Path 2. See Table 2 for operation details.
29	AMP_OUT_2	Driver Amplifier Output (50Ω), Path 2. Connect a pullup inductor from AMP_OUT_2 to $V_{CC_}$.

Dual 50MHz to 1000MHz High-Linearity, Serial/Analog-Controlled VGA

Pin Description (continued)

PIN	NAME	FUNCTION
30	REG_OUT	Regulator Output. Bypass with 1µF capacitor.
31	AMPSET	Driver Amplifier Bias Setting for 3.3V Operation. Set to logic 1 for 3.3V operation on pins $V_{CC_AMP_1}$ and $V_{CC_AMP_2}$. Set to logic 0 for 5V operation.
32	AMP_OUT_1	Driver Amplifier Output (50Ω), Path 1. Connect a pullup inductor from AMP_OUT_1 to $V_{CC_}$.
34	PD_1	Power-Down, Path 1. See Table 2 for operation details.
35	AMP_IN_1	Driver Amplifier Input (50Ω), Path 1. Requires a DC-blocking capacitor. Connect to A_ATT_OUT_1 through a 1000pF capacitor.
37	$V_{CC_AMP_1}$	Driver Amplifier Supply Voltage Input, Path 1. Bypass with a 10nF capacitor as close as possible to the pin.
38	A_ATT_OUT_1	Analog Attenuator Output (50Ω), Path 1. Requires a DC-blocking capacitor. Connect to AMP_IN_1 through a 1000pF capacitor.
39	A_VCTL_1	Analog Attenuator Voltage-Control Input, Path 1. Bypass to ground with a 150pF capacitor if on-chip DAC is used (AA_SP = 1).
40	AA_SP	DAC Enable/Disable Logic Input for Analog Attenuators. Set AA_SP to logic 1 to enable on-chip DAC circuit and digital SPI control. Set AA_SP to logic 0 to disable DAC circuit and digital SPI control. When AA_SP = 0, use analog control lines (A_VCTL_1 and A_VCTL_2).
41	A_ATT_IN_1	Analog Attenuator Input (50Ω), Path 1. Requires a 1000pF DC-blocking capacitor.
—	EP	Exposed Pad. Internally connected to GND. Connect to a large PCB ground plane for proper RF performance and enhanced thermal dissipation.

Detailed Description

The MAX2064 high-linearity analog VGA is a general-purpose, high-performance amplifier designed to interface with 50Ω systems operating in the 50MHz to 1000MHz frequency range.

Each channel of the device integrates an analog attenuator to provide 33dB of total gain control, as well as a driver amplifier optimized to provide high gain, high IP3, low NF, and low power consumption.

Each analog attenuator is controlled using an external voltage or through the SPI-compatible interface using an on-chip 8-bit DAC. See the *Applications Information* section and Table 3 for attenuator programming details.

Because each of the two stages in the separate signal paths has its own RF input and RF output, this component can be configured to either optimize NF (amplifier configured first) or OIP3 (amplifier last). The device's performance features include 24dB amplifier gain (amplifier only), 4.4dB NF at maximum gain (includes attenuator insertion losses), and a high OIP3 level of +41dBm. Each of these features makes the device an ideal VGA for multipath receiver and transmitter applications.

In addition, the device operates from a single +5V supply with full performance, or a +3.3V supply for an enhanced power-savings mode with lower performance. The device is available in a compact 48-pin TQFN package (7mm x 7mm) with an exposed pad. Electrical performance is guaranteed over the extended temperature range, from T_C = -40°C to +85°C.

Analog Attenuator Control

The device integrates two analog attenuators. Each analog attenuator has a 33dB range and is controlled using an external voltage, or through the 3-wire SPI interface using an on-chip 8-bit DAC. See the *Applications Information* section and Table 3 for attenuator programming details. The attenuators can be used for both static and dynamic power control.

Note that when the analog attenuators are controlled by the DACs through the SPI bus, the DAC output voltage shows on A_VCTL_1 and A_VCTL_2 (pins 39 and 22, respectively). Therefore, in SPI mode, the A_VCTL_1 and A_VCTL_2 pins must only connect to the resistor and capacitor to ground, as shown in the *Typical Application Circuit*.

Table 1. Control Logic

AA_SP	ANALOG ATTENUATOR	D/A CONVERTER
0	Controlled by external control voltage	Disabled
1	Controlled by on-chip DAC	Enabled (DAC output voltage shows on A_VCTL__ pins); DAC uses on-chip voltage reference

Table 2. Operating Modes

RESULT	V_{CC} (V)	AMP_SET	PD_1	PD_2
All on	5	0	0	0
	3.3	1	0	0
AMP1 off AMP2 on	5	0	1	0
	3.3	1	1	0
AMP1 on AMP2 off	5	0	0	1
	3.3	1	0	1
All off	5	0	1	1
	3.3	1	1	1

Driver Amplifier

Each path of the device includes a high-performance driver with a fixed gain of 24dB. The driver amplifier circuits are optimized for high linearity for the 50MHz to 1000MHz frequency range.

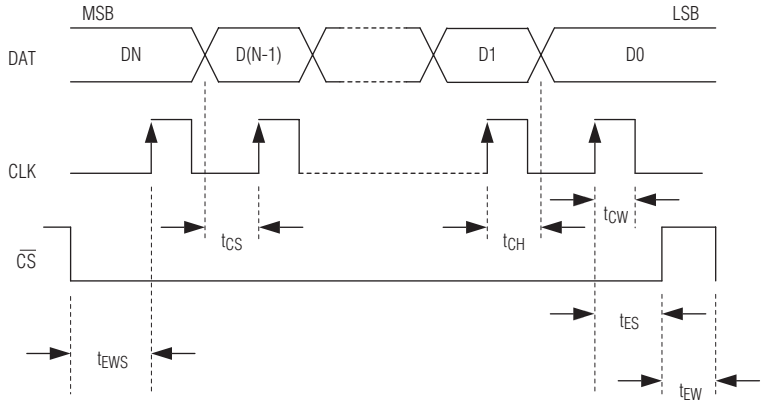
Applications Information

Operating Modes

The device features an optional +3.3V supply voltage operation with reduced linearity performance. The AMPSET pin needs to be biased accordingly in each mode, as listed in Table 2. In addition, the driver amplifiers can be shut down independently to conserve DC power. See the biasing scheme outlined in Table 2 for details.

SPI Interface and Attenuator Settings

The attenuators can be programmed through the 3-wire SPI/MICROWIRE™-compatible serial interface using 5-bit words. Fifty-six bits of data are shifted in MSB first and are framed by $\overline{CS}$. The first 28 bits set the first attenuator and the following 28 bits set the second attenuator. When $\overline{CS}$ is low, the clock is active and data is shifted on the rising edge of the clock. When $\overline{CS}$ transitions high, the data is latched and the attenuator setting changes (Figure 1). See Table 3 for details on the SPI data format.



NOTES: DATA ENTERED ON CLOCK RISING EDGE.
ATTENUATOR REGISTER STATE CHANGE ON $\overline{CS}$ RISING EDGE.
N = NUMBER OF DATA BITS.
D0 IS AN ADDRESS BIT, D1/DN ARE DATA BITS (WHERE N ≤ 20).

Figure 1. SPI Timing Diagram

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Table 3. SPI Data Format

FUNCTION	BIT	DESCRIPTION
Reserved	D55 (MSB)	Bits D[55:36] are reserved. Set to logic 0.
	D54	
	D53	
	D52	
	D51	
	D50	
	D49	
	D48	
	D47	
	D46	
	D45	
	D44	
	D43	
	D42	
	D41	
	D40	
	D39	
	D38	
	D37	
	D36	
On-Chip DAC (Path 2)	D35	Bit 7 (MSB) of on-chip DAC used to program the Path 2 analog attenuator
	D34	Bit 6 of DAC
	D33	Bit 5 of DAC
	D32	Bit 4 of DAC
	D31	Bit 3 of DAC
	D30	Bit 2 of DAC
	D29	Bit 1 of DAC
	D28	Bit 0 (LSB) of DAC

Table 3. SPI Data Format (continued)

FUNCTION	BIT	DESCRIPTION
Reserved	D27	Bits D[27:8] are reserved. Set to logic 0.
	D26	
	D25	
	D24	
	D23	
	D22	
	D21	
	D20	
	D19	
	D18	
	D17	
	D16	
	D15	
	D14	
	D13	
	D12	
	D11	
	D10	
	D9	
	D8	
On-Chip DAC (Path 1)	D7	Bit 7 (MSB) of on-chip DAC used to program the Path 1 analog attenuator
	D6	Bit 6 of DAC
	D5	Bit 5 of DAC
	D4	Bit 4 of DAC
	D3	Bit 3 of DAC
	D2	Bit 2 of DAC
	D1	Bit 1 of DAC
	D0 (LSB)	Bit 0 (LSB) of DAC

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Power-Supply Sequencing

The sequence to be used is:

1) Power supply
2) Control lines

Layout Considerations

The pin configuration of the device is optimized to facilitate a very compact physical layout of the device and its associated discrete components. The exposed pad (EP) of the device's 48-pin TQFN-EP package provides a low thermal-resistance path to the die. It is important that the PCB on which the device is mounted be designed to conduct heat from the EP. In addition, provide the EP with a low inductance path to electrical ground. The EP **MUST** be soldered to a ground plane on the PCB, either directly or through an array of plated via holes. The layout of the PCB should include proper top-layer ground shielding to isolate the amplifier's inputs and outputs from each other. Shielding between the paths (inputs and outputs) is important for channel-to-channel isolation.

Table 4. Typical Application Circuit Component Values

DESIGNATION	QTY	DESCRIPTION	COMPONENT SUPPLIER
C1, C5, C6, C8, C12, C13	6	1000pF ceramic capacitors (0402) GRM1555C1H102J	Murata Electronics North America, Inc.
C3, C10	2	150pF ceramic capacitors (0402) GRM1555C1H151J	Murata Electronics North America, Inc.
C4, C7, C11, C14, C16	5	10nF ceramic capacitors (0402) GRM155R71E103K	Murata Electronics North America, Inc.
C15	1	1µF ceramic capacitor (0603) GRM188R71C105K	Murata Electronics North America, Inc.
L1, L2*	2	820nH inductors (1008) Coilcraft 1008CS-821XJLC	Coilcraft, Inc.
R1, R2	2	47.5kΩ resistors (0402)	—
U1	1	48 TQFN-EP (7mm x 7mm) Maxim MAX2064ETM+	Maxim Integrated Products, Inc.

**Select the inductors to ensure that self-resonance of the inductors is outside the band of operation.*

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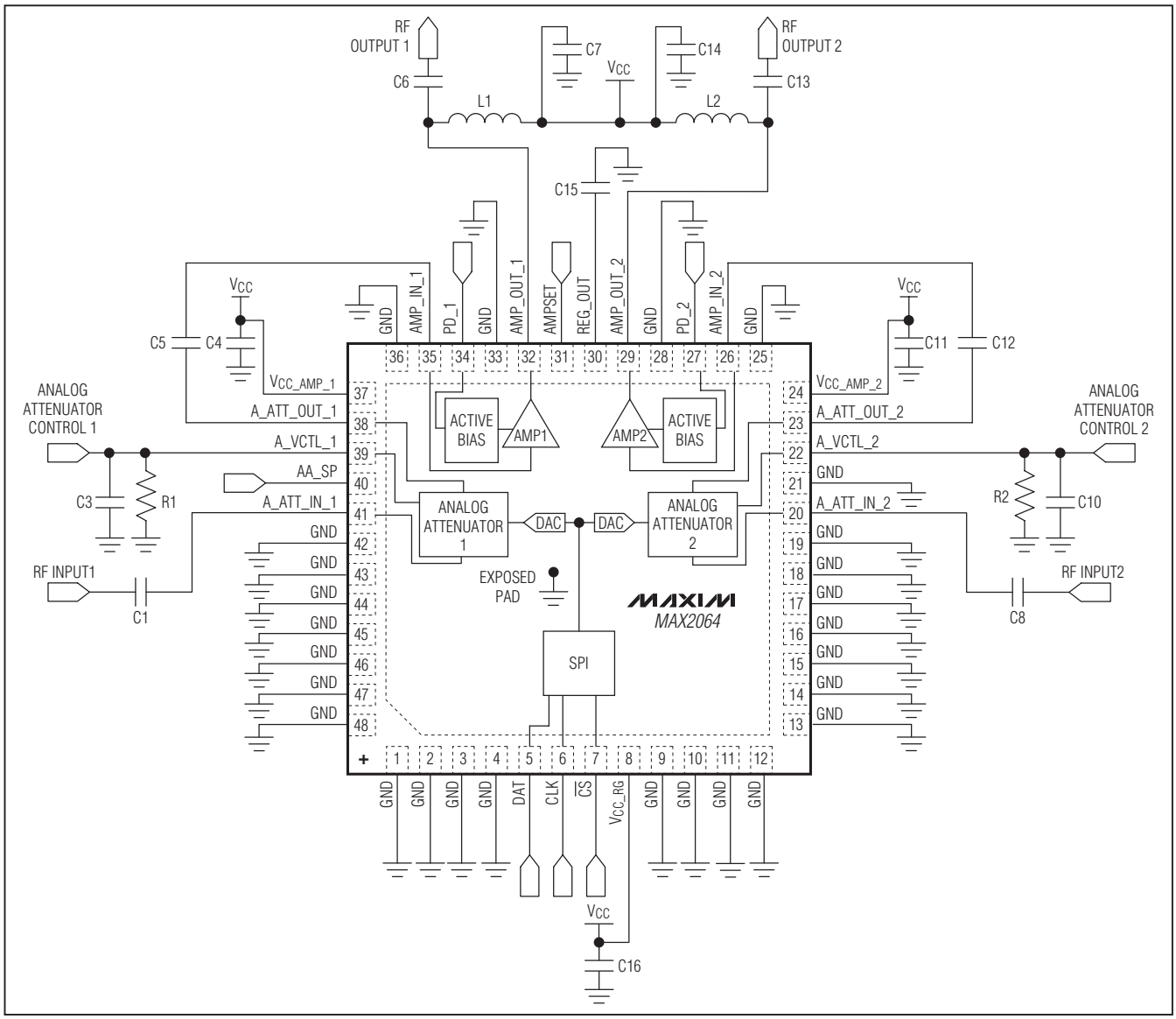
Typical Application Circuit



Chip Information

PROCESS: SiGe BiCMOS

Package Information

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
48 TQFN-EP	T4877+7	21-0144	90-0133

Dual 50MHz to 1000MHz High-Linearity, Serial/Analog-Controlled VGA

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	12/10	Initial release	—

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